17-27GHz Variable Gain Amplifier

Preliminary

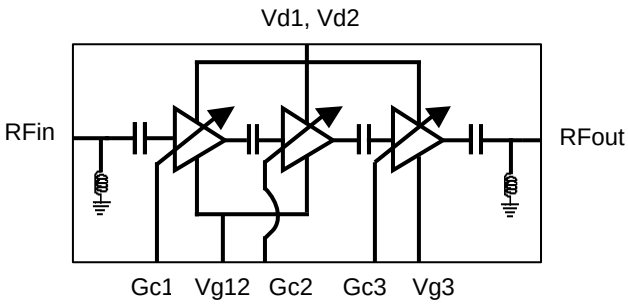
GaAs Monolithic Microwave IC in SMD package

Description

The P014458-QGG is a variable gain broadband three-stage monolithic amplifier.
It is designed for a wide range of applications, typically commercial communication systems.

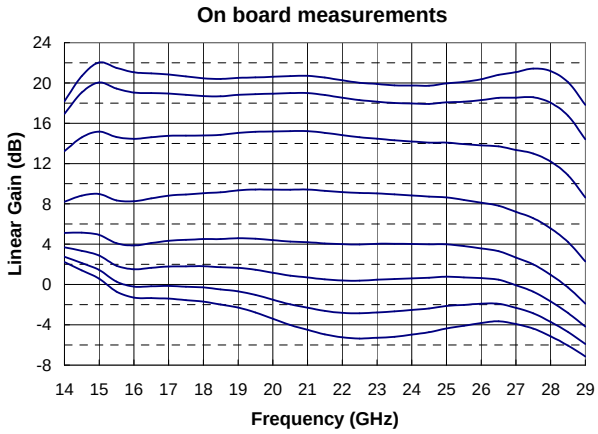
The circuit is manufactured with a power pHEMT process, 0.15µm gate length, via holes through the substrate and air bridges.

It is available in lead-free SMD package.



Main Features

- Broadband performance 17-27GHz
- 20dB gain
- 28dBm output IP3 @ gain max
- 24dB gain control range
- 28L-QFN5x5
- ESD protected (see page 13)



Main Characteristics

Tamb. = 25℃, Vd = 4.5V

Symbol	Parameter	Min	Typ	Max	Unit
Fop	Operating frequency range	17		27	GHz
G	Small signal gain		20		dB
Gc	Gain control range		24		dB
OIP3	Output Intercept Point order 3 @ gain max.		28		dBm

ESD Protection : Electrostatic discharge sensitive device. Observe handling precautions !

United Monolithic Semiconductors S.A.S.
Route Départementale 128 - B.P.46 - 91401 Orsay Cedex France
Tel. : +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

Electrical Characteristics

Tamb. = 25°C, $Vd_{1,2}$ = 4.5V, GcX with X=1,2,3

Preliminary

Symbol	Parameter	Min	Typ	Max	Unit
Fop	Operating frequency range	17		27	GHz
G	Nominal gain @ gain max.		20		dB
NF	Noise Figure @ gain max.		7.5		dB
	Noise Figure @ gain min.		24		dB
RLin	Input Return Loss (Fop<21GHz) (any GcX)		-9		dB
	Input Return Loss (Fop>21GHz) (any GcX)		-12		dB
RLout	Output Return Loss (Fop<21GHz) (any GcX)		-9		dB
	Output Return Loss (Fop>21GHz) (any GcX)		-12		dB
OIP3	Output Intercept Point order 3 @ gain max.		28		dBm
	Output Intercept Point order 3 @ gain min.		19		dBm
P1dB	Output Power at 1dB gain compression @ gain max.		22		dBm
Gc	Gain control range (Fop<20GHz)		22		dB
	Gain control range (Fop>20GHz)		24		dB
$Vd_{1,2}$	DC drain voltage		4.5		V
Id	Drain bias current (*)		250		mA
Idc	Drain current at 1dB gain compression		300		mA
$Vg_{12,3}$	Gate bias voltage		-1.2		V
GcX	DC gain control voltage	-2		+0,6	V

(*) Id not affected by GcX.

These values are representative of on board measurements as defined on the drawing 97263 (see page 15).

Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

united monolithic semiconductors

Preliminary

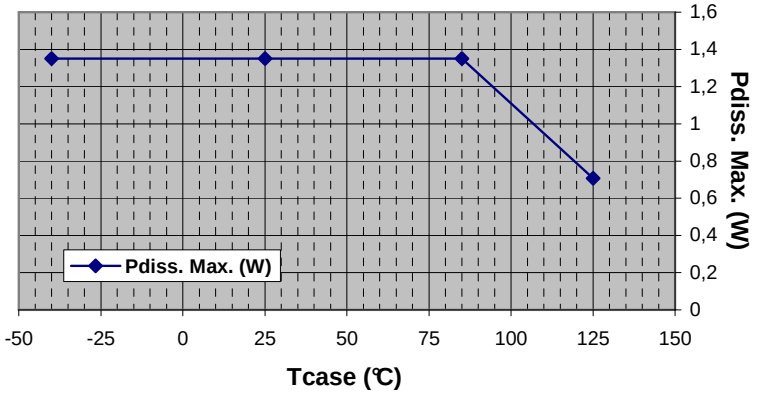
Absolute Maximum Ratings (*)

Tamb = +25℃

Symbol	Parameter	Values	Unit
$Vd_{1,2}$	Drain bias voltage	5	V
Id	Power supply quiescent current	300	mA
Vg	Gate bias voltage	-2 to 0	V
GcX	DC gain control voltage	-2.5 to +1	V
Pin	RF input power @ gain max.	8	dBm
Top	Operating temperature range	-40 to +85	℃
Tj	Junction temperature	175	℃
Tstg	Storage temperature range	-55 to +125	℃

(*) Operation of this device above anyone of these parameters may cause permanent damage.

DEVICE THERMAL SPECIFICATION : VGA-P014458-QGG			
Max. junction temperature (Tj max)		:	170 ℃
Max. continuous dissipated power @ Tcase=	85 ℃	:	1,35 W
=> Pdiss derating above Tcase=	85 ℃	:	16 mW/℃
Device thermal resistance (Rth)		:	62 ℃/W
Min. package back side operating temperature		:	-40 ℃
Max. package back side operating temperature		:	85 ℃
Min. storage temperature		:	-55 ℃
Max. storage temperature		:	125 ℃



Route Départementale 128, B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0) 1 69 33 03 08 - Fax: +33 (0) 1 69 33 03 09

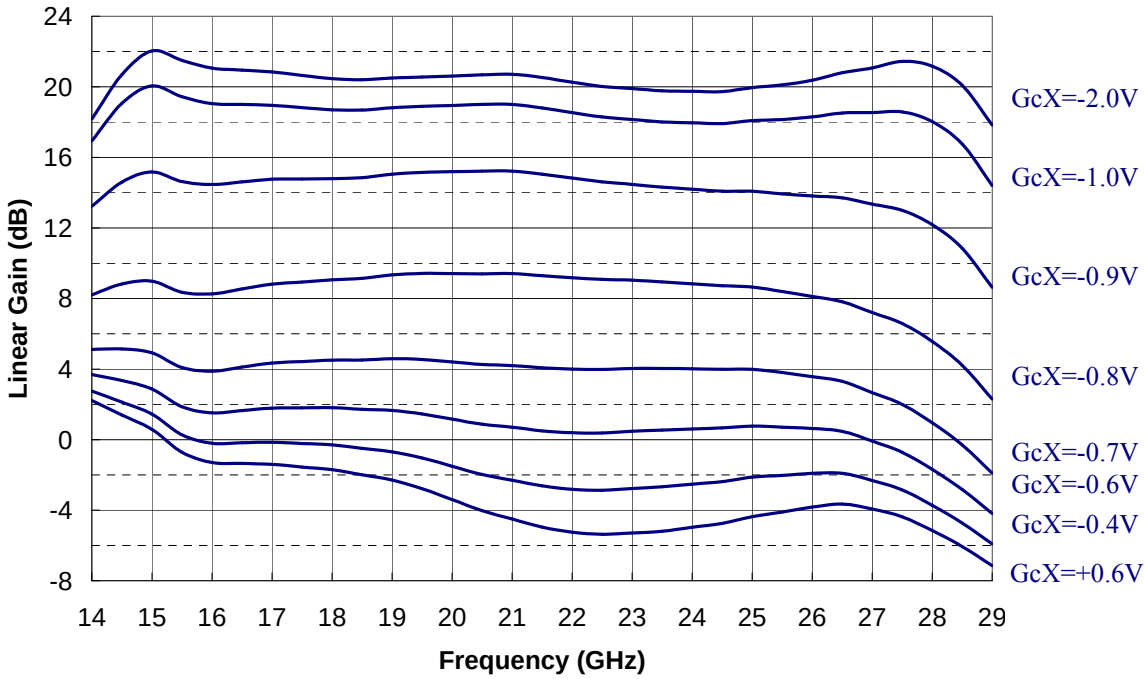
Typical Measured Performance

Preliminary

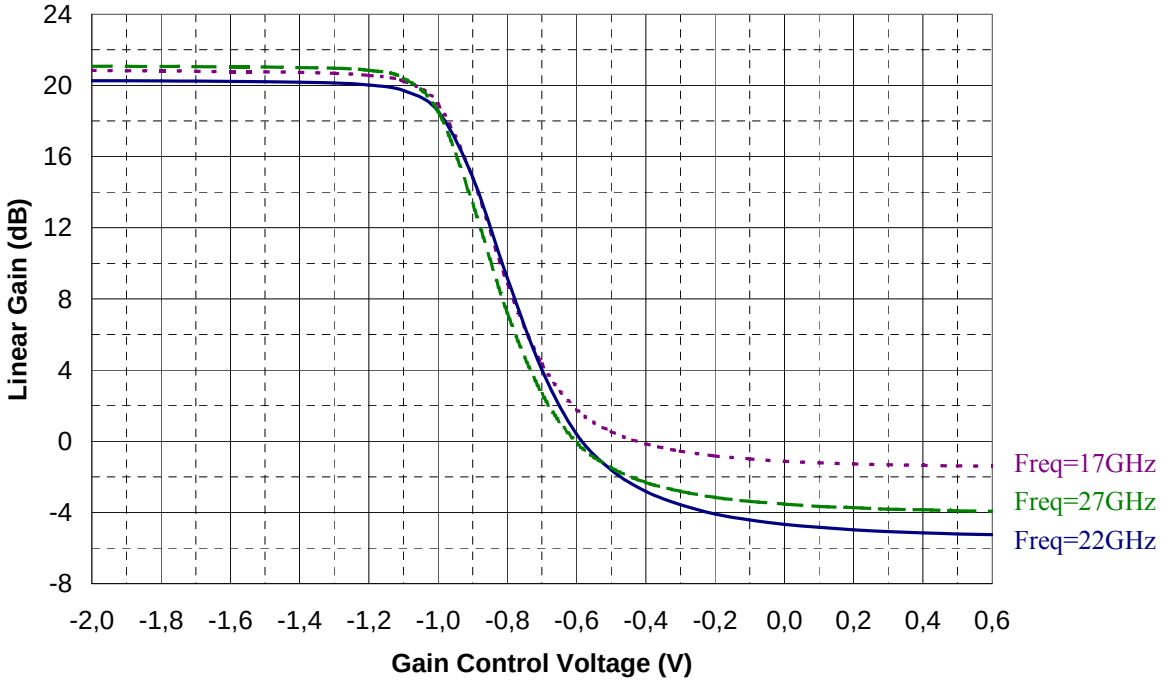
Tamb. = +25°C, $Vd_{1,2}$ = +4.5V, $Vg_{12,3}$ tuned for Id = 250mA

Measurements in the package access planes, using the proposed land pattern & board 97263, as defined page 15.

Linear Gain versus Frequency



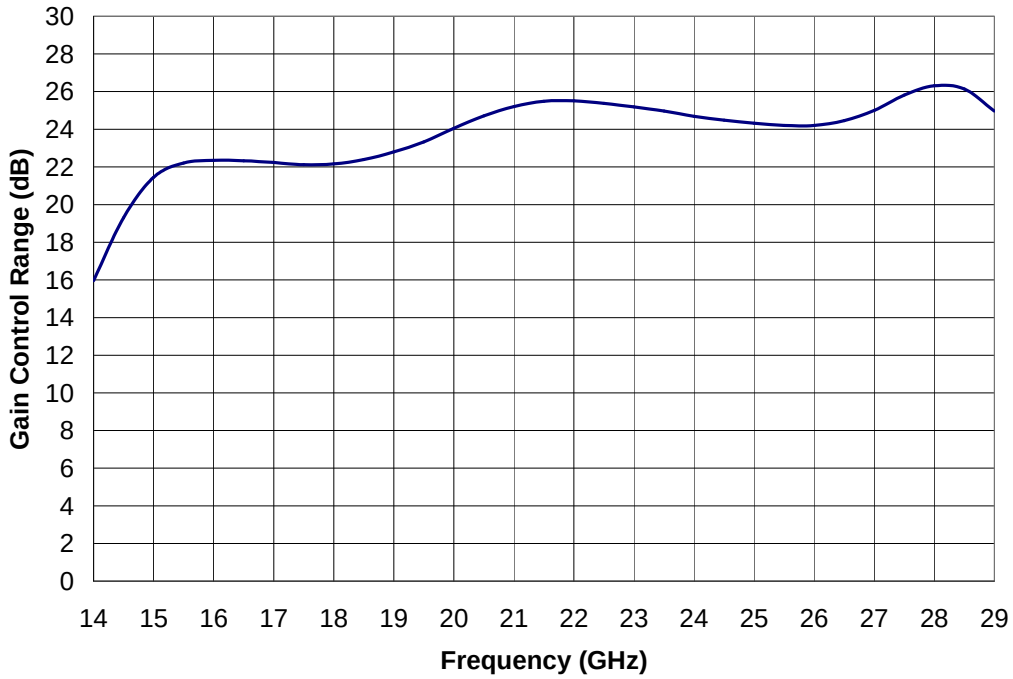
Linear Gain versus Gain Control Voltage



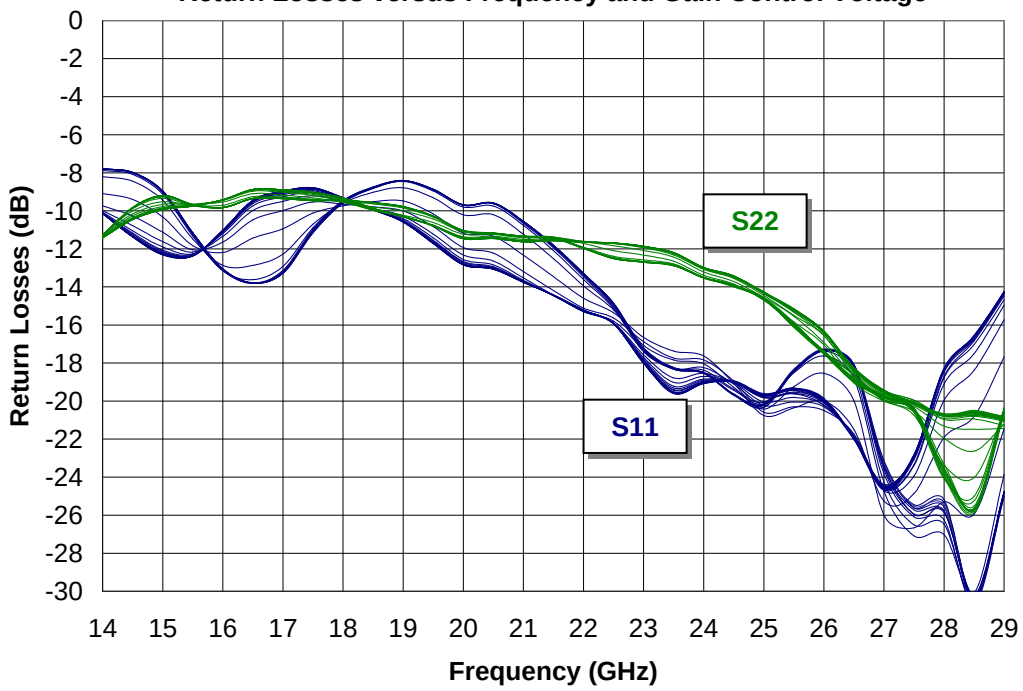
Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

Preliminary

Gain Control Range versus Frequency



Return Losses versus Frequency and Gain Control Voltage



Route Départementale 128, B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0) 1 69 33 03 08 - Fax: +33 (0) 1 69 33 03 09

Typical Package Sij parameters for GcX = -2.0V

Preliminary

Tamb. = +25°C, $Vd_{1,2}$ = +4.5V, Id = 250mA

Freq (GHz)	dB(S11)	Ph(S11) (°)	dB(S12)	Ph(S12) (°)	dB(S2 1)	Ph(S21) (°)	dB(S22)	Ph(S22) (°)
2,0	-1,6	105	-62,6	-93	-35,2	-166	-10,7	74
3,0	-3,2	55	-64,1	-151	-26,3	-30	-6,2	152
4,0	-6,8	-11	-84,6	64	-35,7	-141	-1,8	109
5,0	-11,6	-104	-75,6	162	-29,5	51	-1,9	74
6,0	-11,1	173	-69,7	66	-16,8	-70	-2,7	40
7,0	-9,6	125	-62,7	56	-11,8	-167	-4,0	7
8,0	-8,0	93	-62,1	5	-6,5	121	-6,5	-26
9,0	-7,6	58	-63,1	-28	-3,1	50	-10,3	-50
10,0	-8,0	23	-64,2	-90	-0,5	-16	-14,5	-61
11,0	-7,4	-10	-64,7	-128	3,5	-72	-14,9	-57
12,0	-7,8	-47	-64,2	176	7,0	-133	-14,5	-64
13,0	-7,1	-78	-70,6	-173	12,6	167	-13,2	-71
14,0	-7,8	-109	-57,9	163	18,2	92	-11,3	-78
15,0	-9,0	-134	-50,7	110	22,0	-5	-9,2	-100
16,0	-13,1	-152	-51,1	57	21,1	-99	-9,8	-119
17,0	**-13,3**	**-132**	**-52,8**	**36**	**20,8**	**-173**	**-9,4**	**-132**
17,5	**-11,2**	**-128**	**-52,4**	**28**	**20,7**	**152**	**-9,5**	**-139**
18,0	**-9,6**	**-133**	**-53,6**	**19**	**20,5**	**118**	**-9,5**	**-144**
18,5	**-8,8**	**-146**	**-53,7**	**12**	**20,4**	**84**	**-9,6**	**-151**
19,0	**-8,4**	**-158**	**-53,0**	**0**	**20,5**	**49**	**-9,8**	**-159**
19,5	**-8,9**	**-169**	**-55,7**	**-2**	**20,6**	**13**	**-10,3**	**-165**
20,0	**-9,7**	**179**	**-54,9**	**-9**	**20,6**	**-24**	**-11,0**	**-172**
20,5	**-9,6**	**174**	**-58,8**	**-29**	**20,7**	**-58**	**-11,2**	**-176**
21,0	**-10,6**	**161**	**-60,3**	**16**	**20,7**	**-94**	**-11,3**	**-179**
21,5	**-11,8**	**150**	**-56,0**	**32**	**20,5**	**-131**	**-11,4**	**174**
22,0	**-13,3**	**137**	**-54,6**	**3**	**20,3**	**-167**	**-12,0**	**168**
22,5	**-14,9**	**134**	**-54,3**	**1**	**20,0**	**157**	**-12,5**	**162**
23,0	**-17,2**	**139**	**-55,6**	**18**	**19,9**	**122**	**-12,7**	**154**
23,5	**-18,3**	**134**	**-54,2**	**17**	**19,8**	**86**	**-12,9**	**145**
24,0	**-18,5**	**130**	**-52,0**	**33**	**19,8**	**47**	**-13,5**	**132**
24,5	**-19,7**	**132**	**-48,1**	**23**	**19,7**	**13**	**-13,9**	**121**
25,0	**-20,3**	**119**	**-46,1**	**15**	**20,0**	**-25**	**-14,6**	**102**
25,5	**-18,4**	**102**	**-45,0**	**-7**	**20,1**	**-64**	**-16,1**	**86**
26,0	**-17,3**	**81**	**-43,5**	**-7**	**20,4**	**-104**	**-17,4**	**75**
26,5	**-18,1**	**52**	**-43,4**	**-21**	**20,8**	**-148**	**-18,9**	**53**
27,0	**-23,1**	**32**	**-43,1**	**-35**	**21,1**	**167**	**-19,8**	**23**
28,0	-25,6	23	-39,4	-54	21,2	60	-23,3	-37
29,0	-24,7	36	-40,6	-72	17,8	-61	-20,5	-44
30,0	-15,8	15	-40,1	-91	9,8	-178	-18,3	-103
31,0	-9,0	-28	-38,5	-111	0,8	86	-15,5	-122
32,0	-6,3	-90	-36,1	-131	-10,4	-5	-13,1	-149
33,0	-3,7	-134	-36,4	-167	-20,6	-85	-10,5	-167
34,0	-2,6	-169	-40,1	157	-29,4	-161	-7,8	178
35,0	-1,4	164	-42,7	139	-37,1	146	-5,5	160
36,0	-1,7	138	-46,8	119	-43,1	97	-4,1	142
37,0	0,4	127	-55,8	-165	-52,9	152	-2,3	128
38,0	-0,1	109	-46,0	143	-43,0	117	-1,1	112
39,0	-0,1	95	-48,7	135	-48,2	144	-0,5	99
40,0	-1,1	82	-50,9	90	-50,0	57	-0,6	87

Refer to the “definition of the Sij reference planes” section below.

Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

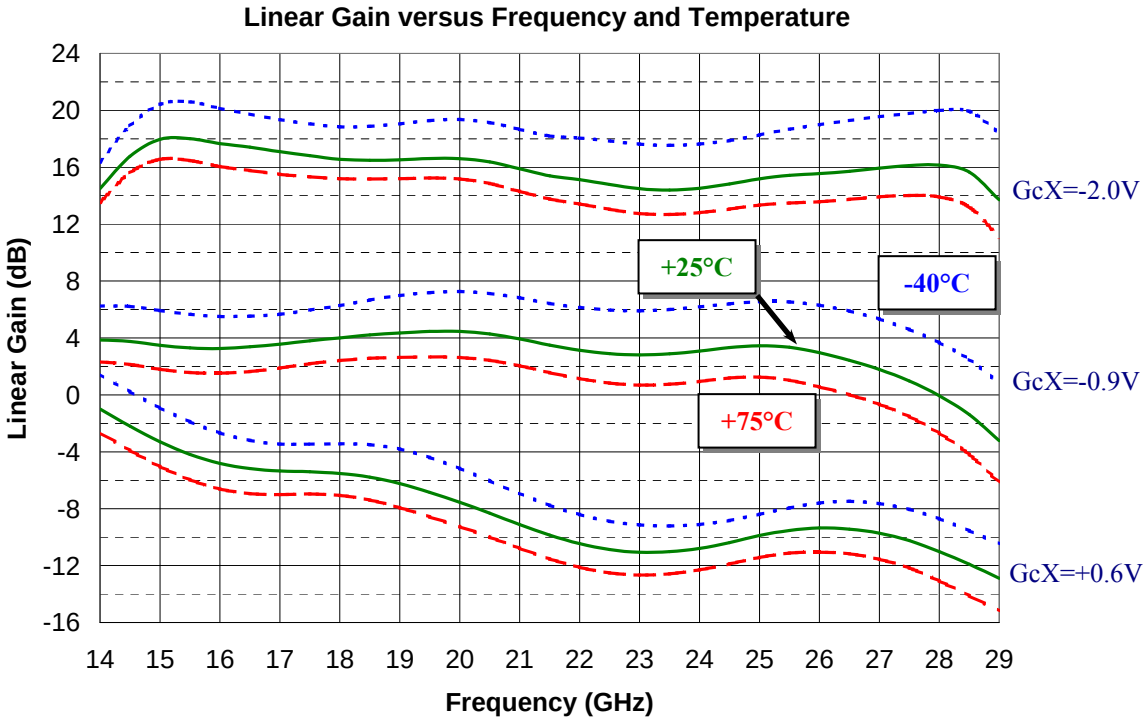
united monolithic semiconductors

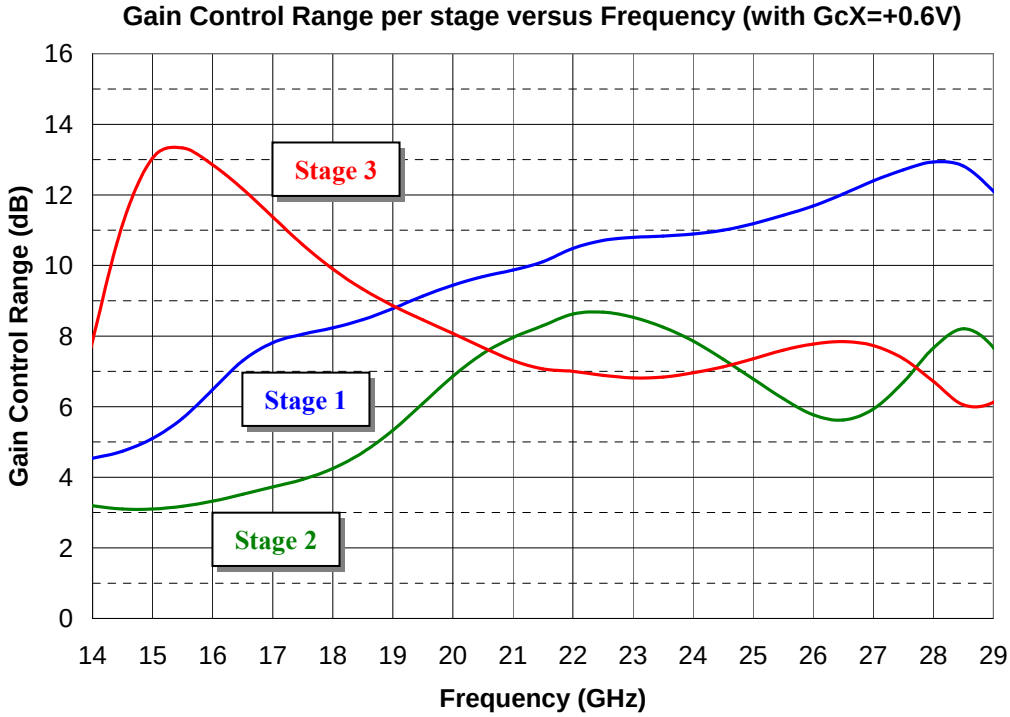
Typical Measured Performance

Preliminary

Tamb. = +25°C, $Vd_{1,2}$ = +4.5V, $Vg_{12,3}$ tuned for Id = 250mA

Measurements in the plan of the connectors (losses not deembeded), using the proposed land pattern & board 97263, as defined page 15.

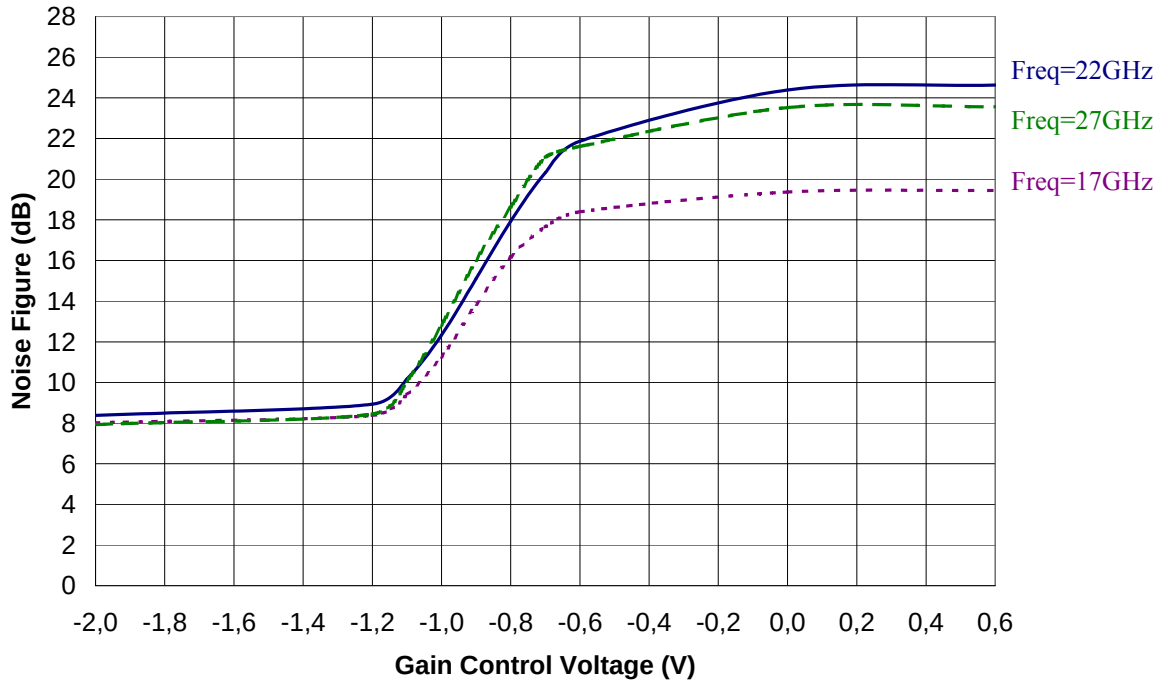




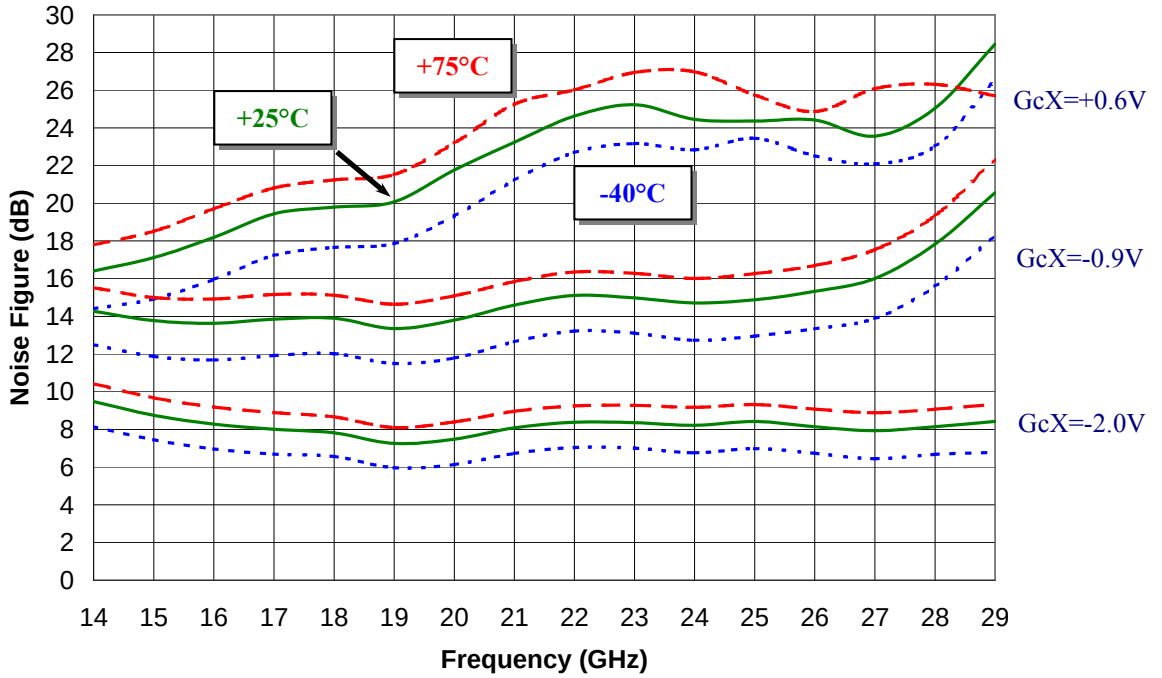
Route Départementale 128, B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0) 1 69 33 03 08 - Fax: +33 (0) 1 69 33 03 09

Preliminary

Noise Figure versus Gain Control Voltage @ 25°C



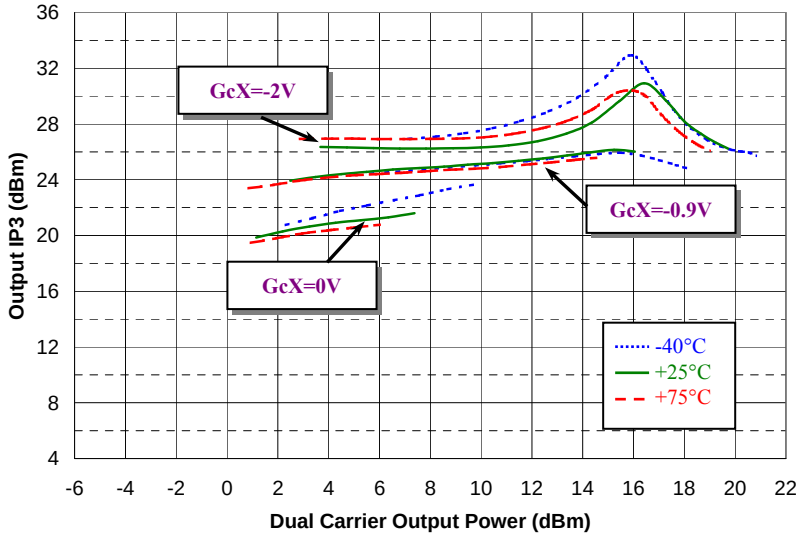
Noise Figure versus Frequency and Temperature



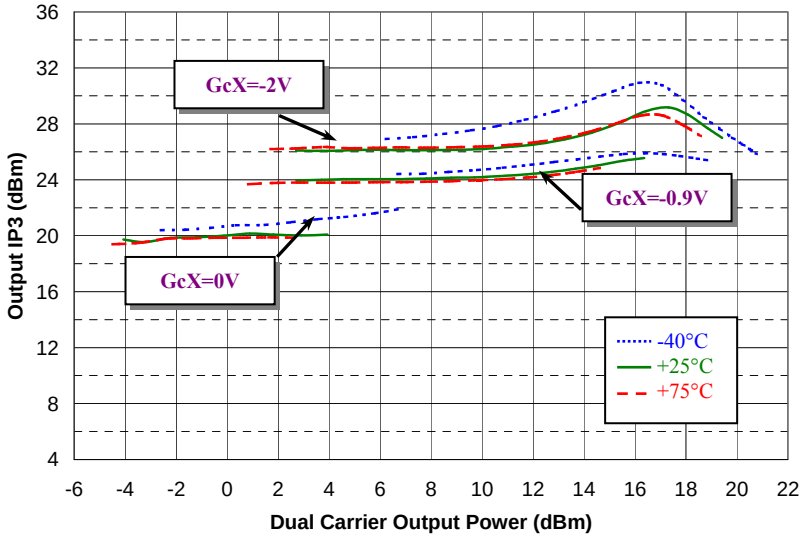
Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

Preliminary

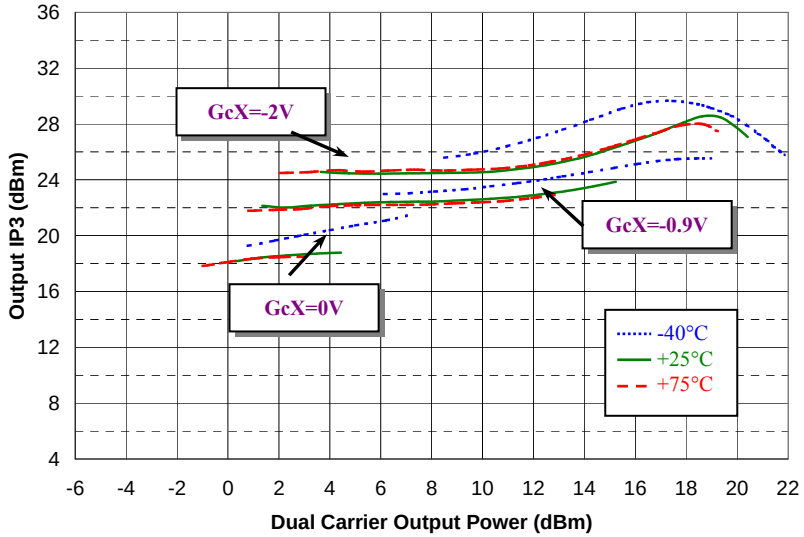
Output IP3 versus Dual Carrier Output Power and Temperature @ 17GHz



Output IP3 versus Dual Carrier Output Power and Temperature @ 21GHz



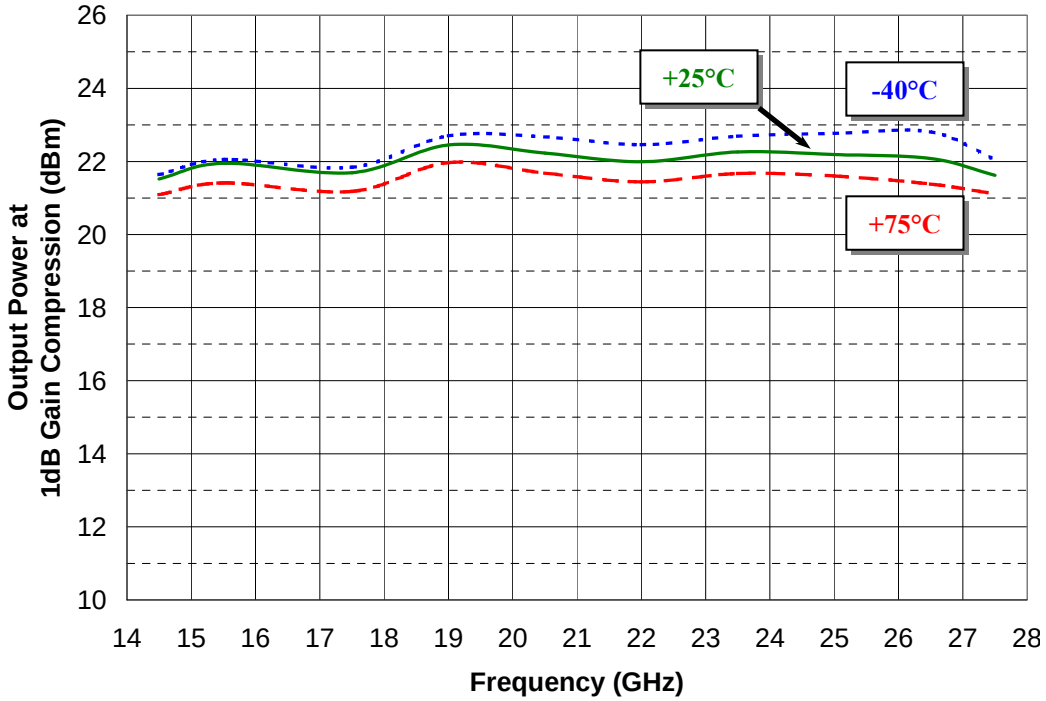
Output IP3 versus Dual Carrier Output Power and Temperature @ 27GHz



Route Départementale 128, B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0) 1 69 33 03 08 - Fax: +33 (0) 1 69 33 03 09

Preliminary

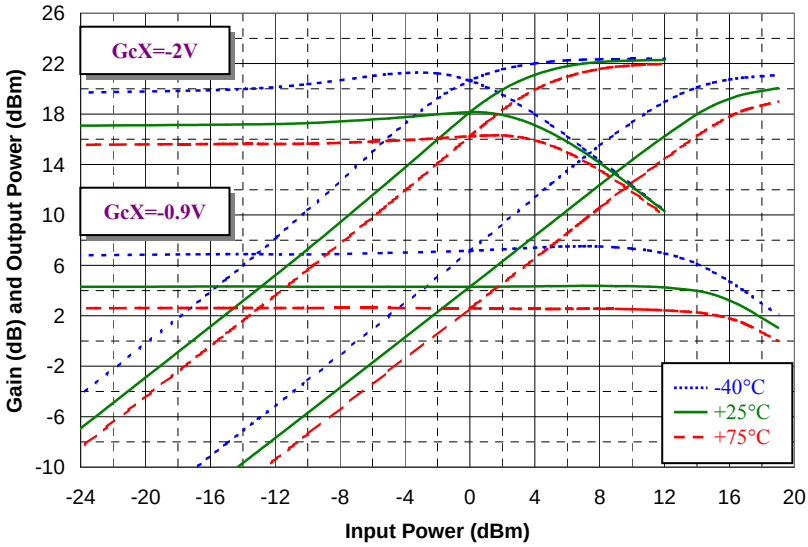
Output Power at 1dB Gain Compression versus Frequency and Temperature for GcX=-2V



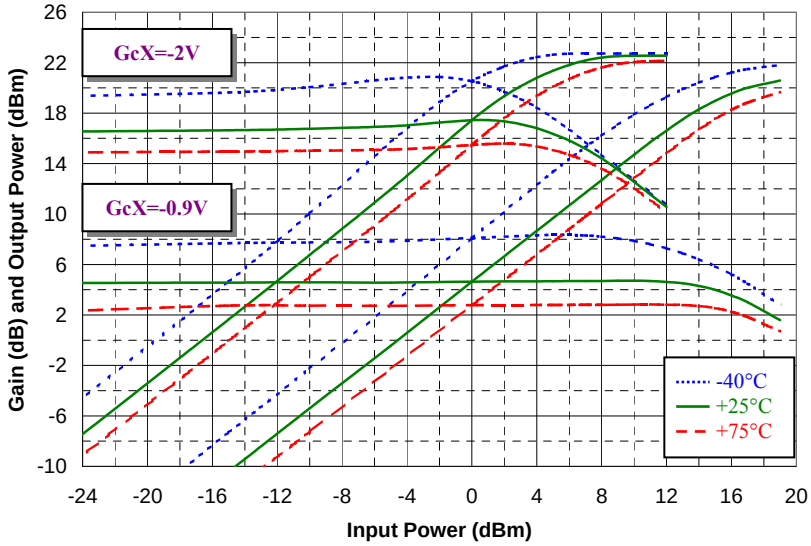
Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

Preliminary

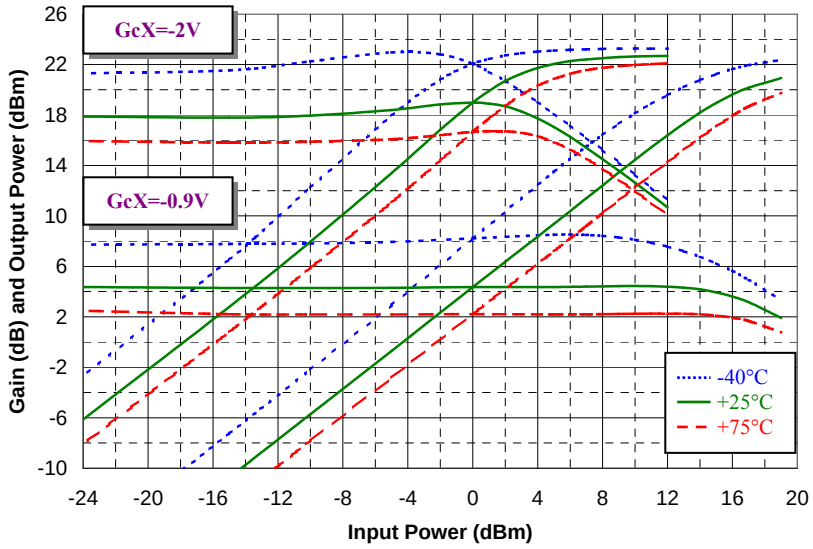
Gain and Output Power versus Input Power and Temperature @ 17.5GHz



Gain and Output Power versus Input Power and Temperature @ 22GHz



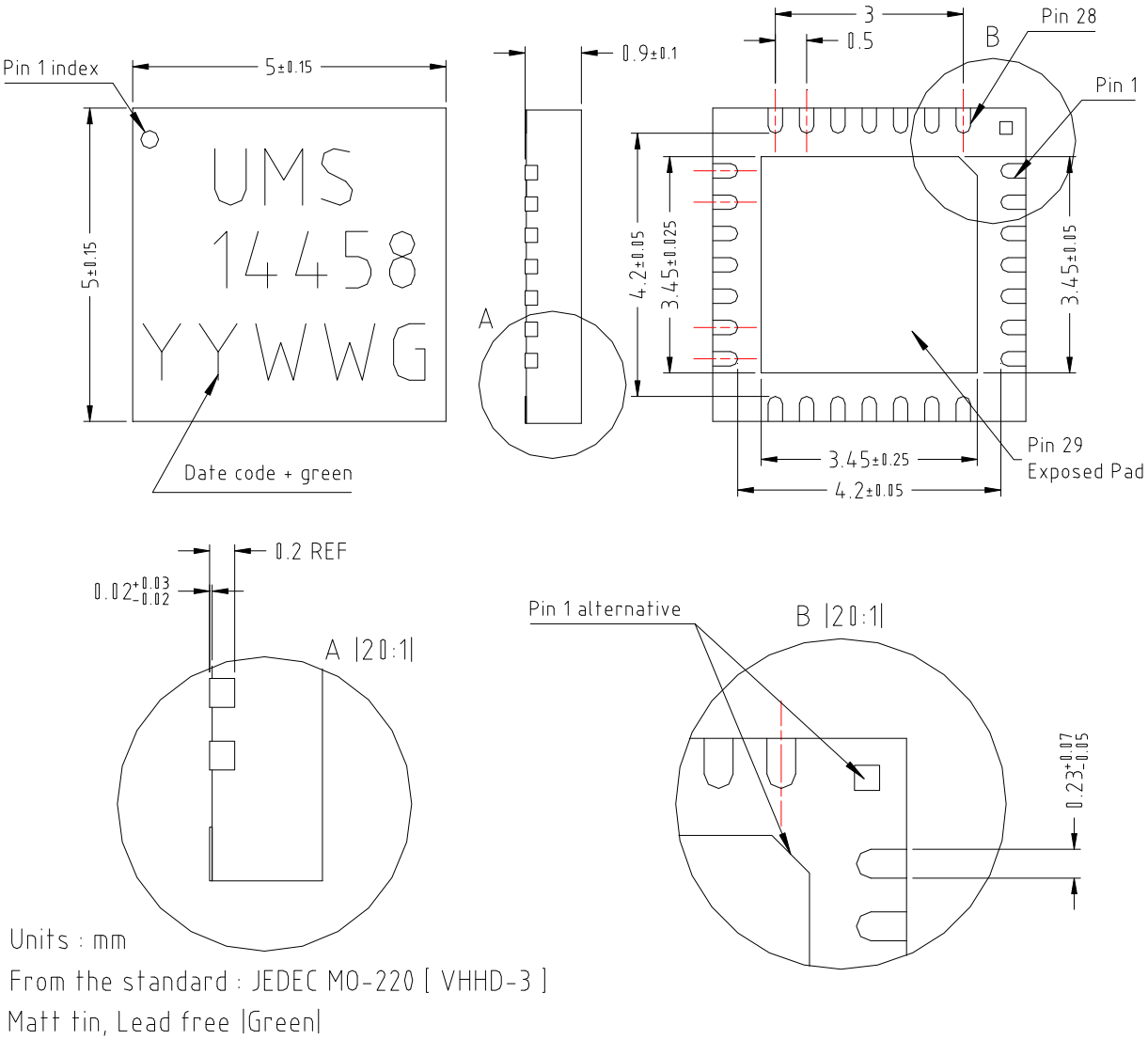
Gain and Output Power versus Input Power and Temperature @ 26.5GHz



Route Départementale 128, B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0) 1 69 33 03 08 - Fax: +33 (0) 1 69 33 03 09

Package outline

Preliminary



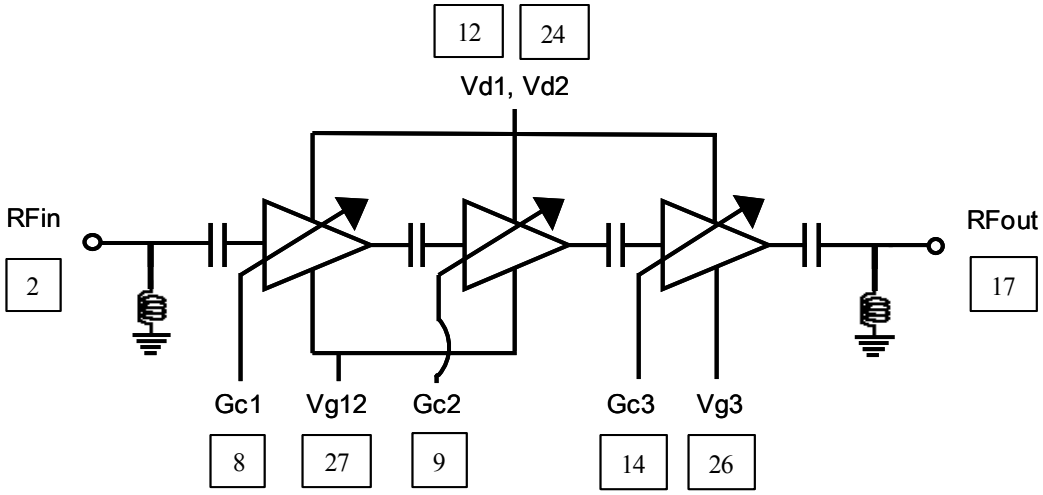
1- Gnd	9- Gc2	17- RF OUT	25- Nc
2- RF IN	10- Nc	18- Gnd	26- Vg3
3- Gnd	11- Nc	19- Gnd	27- Vg12
4- Gnd	12- Vd1	20- Nc	28- Nc
5- Nc	13- Nc	21- Gnd	29- Gnd
6- Gnd	14- Gc3	22- Nc	
7- Gnd	15- Gnd	23- Nc	
8- Gc1	16- Gnd	24- Vd2	

Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

Note

Preliminary

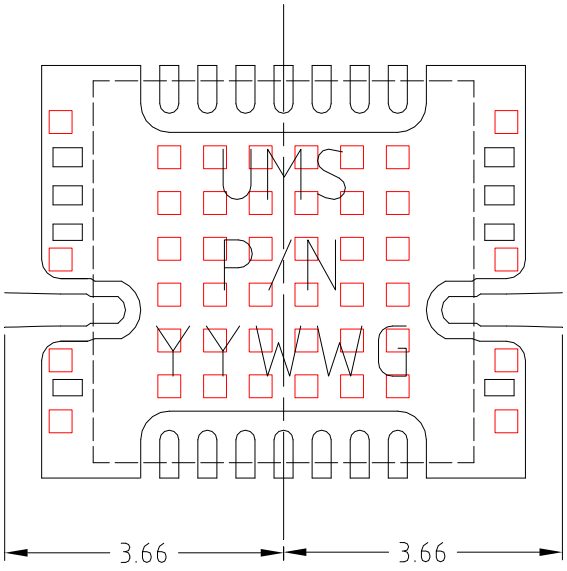
Due to ESD protection circuits on RF input and output, an external capacitance might be requested to isolate the product from external voltage that could be present on the RF accesses.



ESD protections are also implemented on gate accesses.
The DC connections do not include any decoupling capacitor in package, therefore it is mandatory to provide a good external DC decoupling on the PC board, as close as possible to the package.

Definition of the Sij reference planes

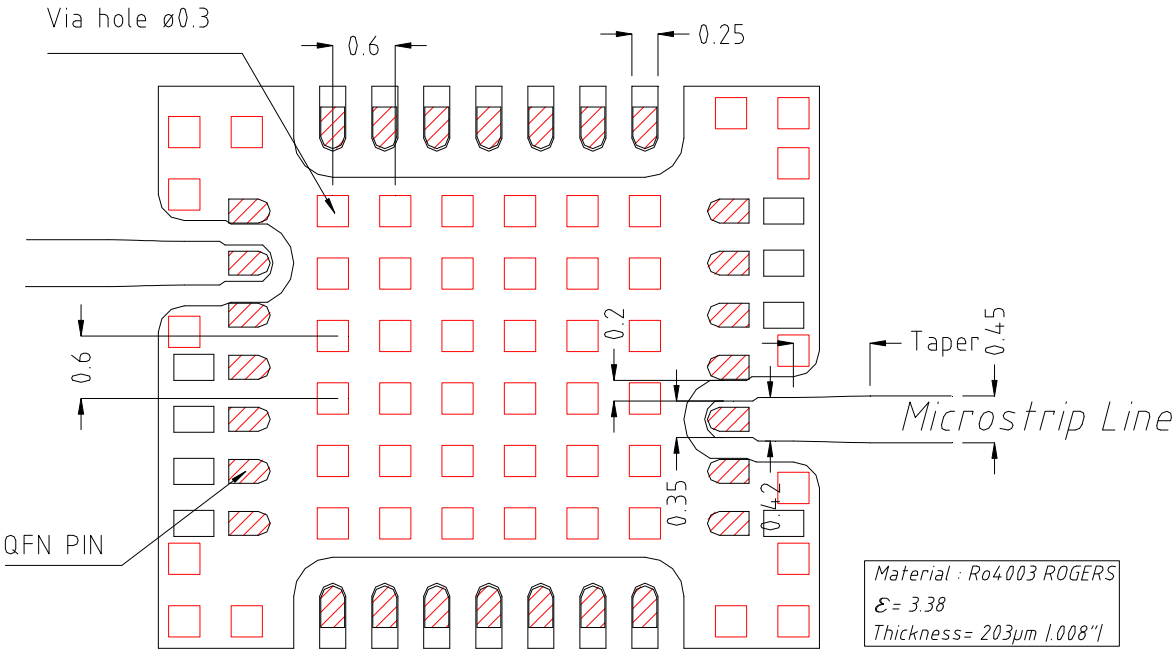
The reference planes are defined from the footprint of the recommended characterization board shown to the right.
The reference is the symmetrical axis of the package. The input and output reference planes are located at 3.66mm offset (input wise and output wise respectively) from this axis. Then, the given Sij incorporates this land pattern.



Route Départementale 128, B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0) 1 69 33 03 08 - Fax: +33 (0) 1 69 33 03 09

Preliminary

Recommended footprint for 28L-QFN5X5



SMD mounting procedure

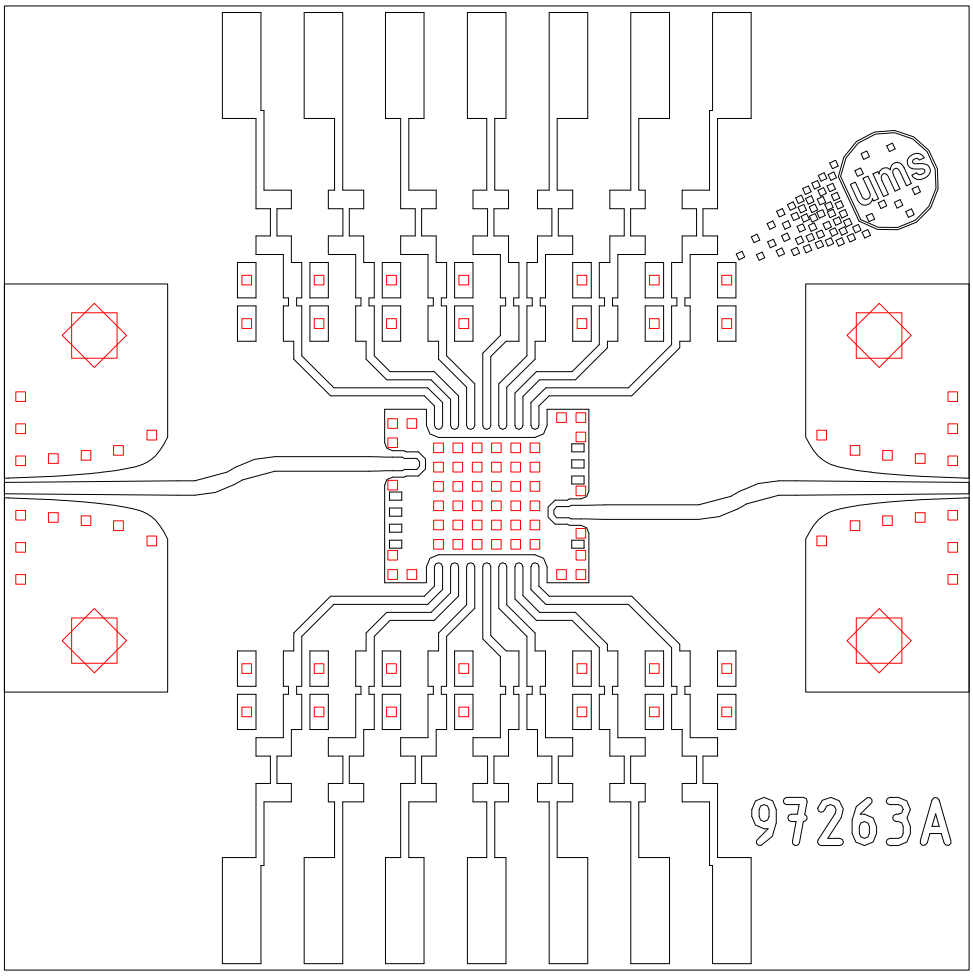
The SMD leadless package has been designed for high volume surface mount PCB assembly process. The dimensions and footprint required for the PCB (motherboard) are given in the drawing above.
For the mounting process standard techniques involving solder paste and a suitable reflow process can be used. For further details, see application note AN0017.

Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

Preliminary

Proposed Assembly board “97263” for the 28L-QFN5x5 products characterization.

- Compatible with the proposed footprint.
- Based on typically Ro4003 / 8mils or equivalent.
- Using a microstrip to coplanar transition to access the package.
- Recommended for the implementation of this product on a module board.



Decoupling capacitors of 10nF ±10% are recommended for all DC accesses.

Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09

Preliminary

Ordering Information

QFN 5x5 RoHS compliant package: VGA-P014458-QGG/XY
Stick: XY = 20 Tape & reel: XY = 21

Route Départementale 128 , B.P.46 - 91401 ORSAY Cedex - FRANCE
Tel.: +33 (0)1 69 33 03 08 - Fax : +33 (0)1 69 33 03 09